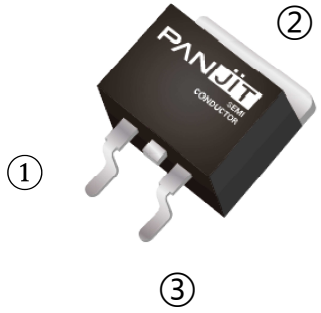
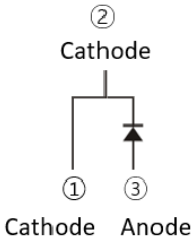
Silicon Carbide Schottky Barrier Diode

V_{RRM}	1200 V	I_F	10 A
$V_{F(Typ.)}$	1.5 V	Q_C	42 nC

TO-263





Features

- Temperature Independent Switching Behavior
- High Surge Current Capability
- Positive Temperature Coefficient on V_F
- Low Conduction Loss
- Zero Reverse Recovery
- High junction temperature 175 °C
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: TO-263 molded plastic
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0487 ounces, 1.38 grams

Application

- PFC, UPS, PV Inverter, Welder

Maximum Ratings and Thermal Characteristics (T_C = 25 °C unless otherwise specified)

PARAMETER		SYMBOL	LIMIT	UNITS
Repetitive Peak Reverse Voltage		V_{RRM}	1200	V
DC Blocking Voltage		V_{DC}	1200	V
Continuous Forward Current	T_C= 155 °C	I_F	10	A
Repetitive Peak Surge Current *Half Sine Wave, D=0.1*	T_C= 25 °C , t_p =10ms T_C=125 °C , t_p =10ms	I_{FRM}	48 40	A
Peak Forward Surge Current *Half Sine Wave*	T_C= 25 °C , t_p =10ms T_C=125 °C , t_p =10ms	I_{FSM}	76 68	A
Peak Forward Surge Current *t_p =10us, Pulse*			640	A
Maximum Power Dissipation		P_{total}	164.8	W
Operating Junction Temperature Range		T_J	-55~175	°C
Storage Temperature Range		T_{STG}	-55~175	°C

Electrical Characteristics (T_C = 25 °C unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Forward Voltage Drop	V_F	I_F = 10 A, T_J = 25 °C	-	1.5	1.7	V
		I_F = 10 A, T_J = 175 °C	-	2.0	-	
Reverse Leakage Current	I_R	V_R = 1200 V, T_J = 25 °C	-	6	100	μA
		V_R = 1200 V, T_J = 175 °C	-	0.085	-	mA
Total Capacitive Charge	Q_C	I_F = 10 A, V_R = 800V	-	42	-	nC
Total Capacitance	C	V_R = 1V, f = 1MHz	-	529	-	pF
		V_R = 400V, f = 1MHz	-	36	-	pF
		V_R = 800V, f = 1MHz	-	25	-	pF
Capacitance Stored Energy	E_C	V_R = 800V	-	12	-	μJ
Thermal Resistance	$R_{\theta JC}$		-	0.91	-	°C/W

TYPICAL CHARACTERISTIC CURVES

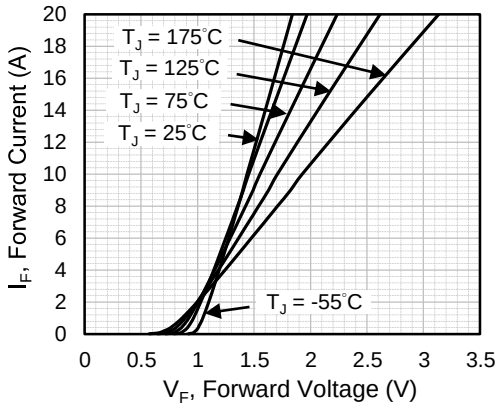


Fig.1 Forward Characteristics

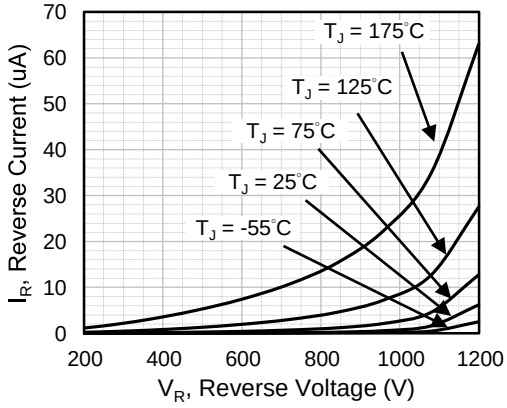


Fig.2 Reverse Characteristics

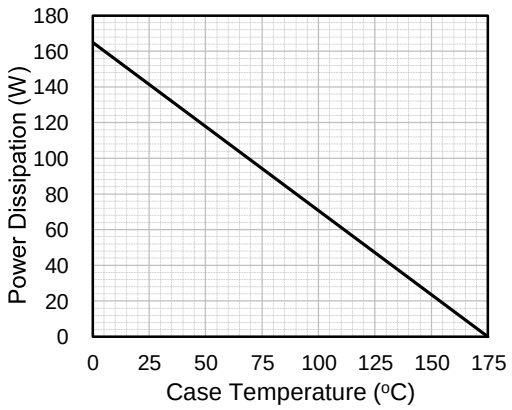


Fig.3 Power Derating Curve

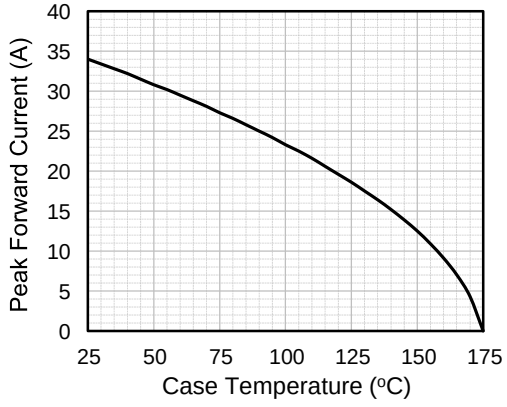


Fig.4 Current Derating Curve

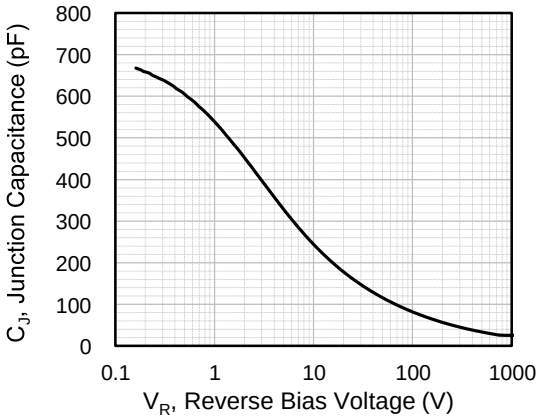


Fig.5 Typical Junction Capacitance

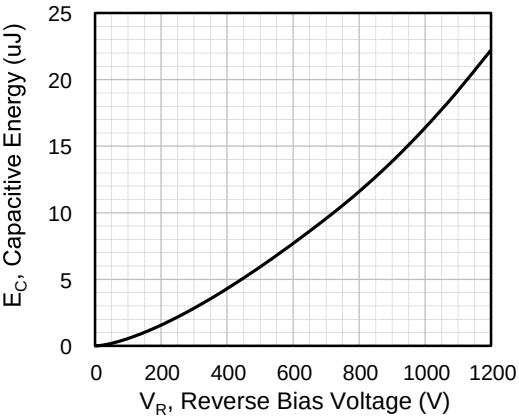


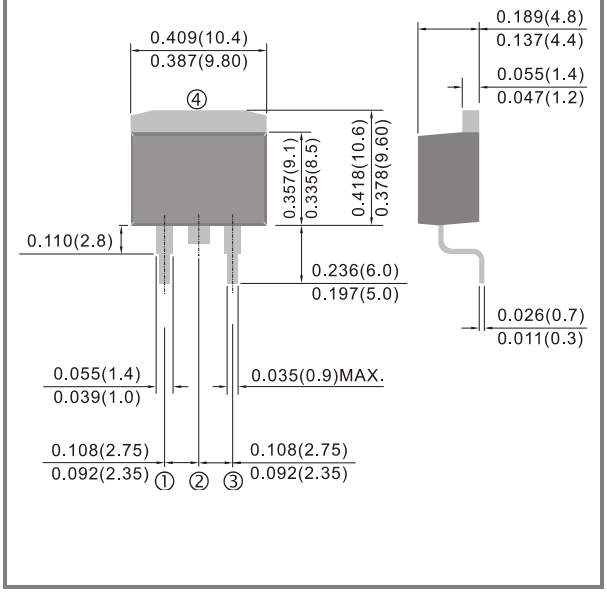
Fig.6 Capacitance Stored Energy

Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PCDB10120G1	TO-263	50pcs / Tube 800pcs / Reel	CDB10120G1

Packaging Information & Mounting Pad Layout

TO-263 Dimension — Unit: inch(mm)



TO-263 Pad Layout — Unit: inch(mm)